

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of:

Kittl et al.

Docket No.: TI-23892

Serial No: TBD

Examiner: TBD

Filed: 12/13/01

Art Unit: TBD

For: METHOD TO IMPROVE SILICIDE FORMATION ON POLYSILICON

PRELIMINARY AMENDMENT

December 19, 2001

Assistant Commissioner for Patents

Washington, DC 20231

Dear Sir:


Please amend the above referenced application as follows:

In the Specification:

Page 1, before line 1, insert --This application claims priority under 35 USC § 119(e)(1) of provisional application number **60/259,401** filed **12/30/00**.

[illegible]

If the Examiner has any questions or other correspondence regarding this application, Applicant requests that the Examiner contact Applicant's attorney at the below listed telephone number and address.


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